



Pb Free

Specification

YG101-IC1

SSC		Customer
Drawn	Approval	Approval

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YG101-IC1

1. Description

- Small size suitable for compact appliances.
- Surface-mounted chip LED device.
- Pb-free and RoHS complaint component.
- High brightness, High efficiency
- Tape and Reel packing.
- Increases the life time of battery.



YG101-IC1

Features

- 1.6 X 0.8 X 0.8 mm
- Untinted, Diffused flat mold
- Dominant Wavelength : 572nm

Applications

- ♦ Cellular phone's keypad lightning
- ♦ Information Boards

2. Absolute maximum ratings

(Ta=25℃)

Parameter	Symbol	Value	Unit
Power Dissipation	P_d	69	mW
Forward Current	I_F	30	mA
Peak Forward Current	I_{FM}^{*1}	100	mA
Operating Temperature	$T_{opr.}$	-40 ~ 85	℃
Storage Temperature	$T_{stg.}$	-40 ~ 100	℃

*1 I_{FM} conditions: Pulse width $T_w \leq 1\text{msec}$ and Duty ratio $\leq 1/10$.

3. Electro-Optical Characteristics

(Ta=25℃)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Forward Voltage	V_F	$I_F = 20\text{mA}$	1.9	2.05	2.3	V
Reverse Current	I_R	$V_R = 5\text{V}$	-	-	10	uA
Luminous Intensity*2	I_v	$I_F = 20\text{mA}$	30	38	53	mcd
Wavelength	λ_d	$I_F = 20\text{mA}$	568	572	576	nm
Spectral Bandwidth	$\Delta\lambda$	$I_F = 20\text{mA}$	-	15	-	nm
Viewing Angle*3 (Y)	$2\theta_{1/2}$	$I_F = 20\text{mA}$	-	140	-	°

*2 The luminous intensity I_v is measured at the peak of the spatial pattern which may not be aligned with the mechanical axis of the LED package.

*3 $\theta_{1/2}$ is the off-axis where the luminous intensity is 1/2 the peak intensity.

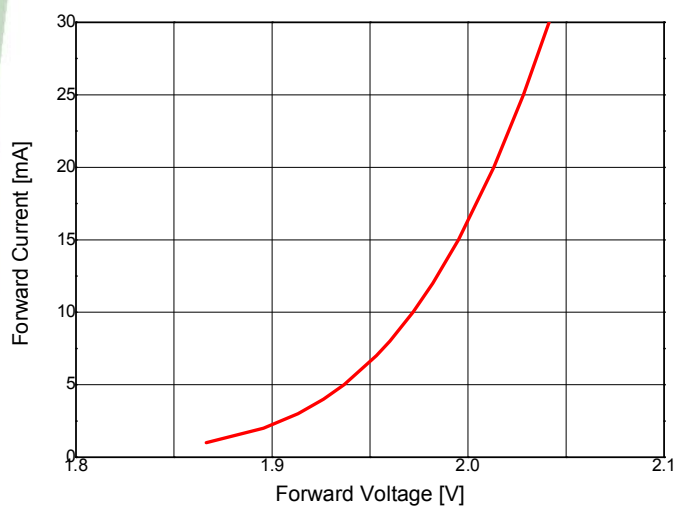
[Note] All measurements were made under the standardized environment of SSC.

(Tolerance : $I_v \pm 10\%$, $\lambda_d \pm 2\text{nm}$, $V_F \pm 0.1\text{V}$)

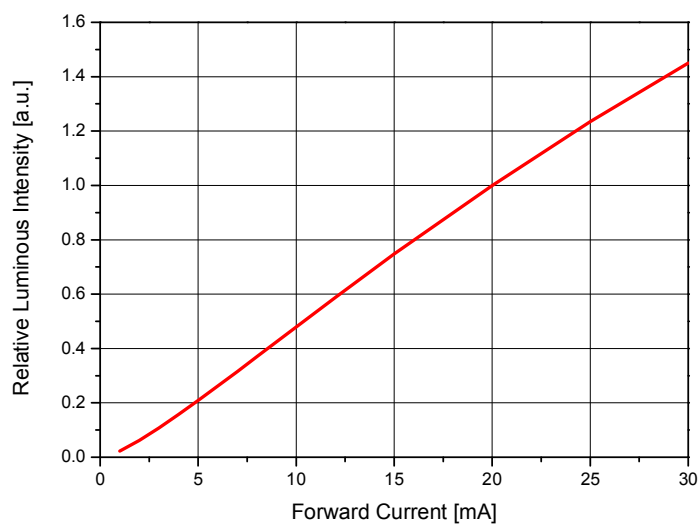
4. Characteristic Diagrams

$T_a = 25^\circ$

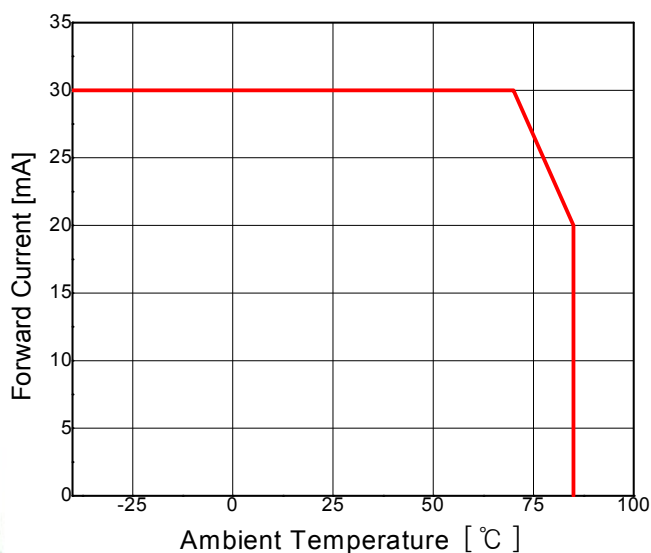
Forward Current vs. Forward Voltage



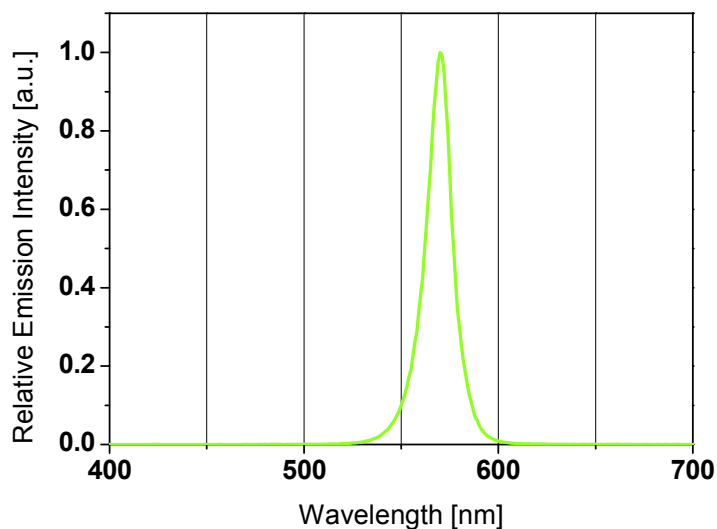
Relative Luminous Intensity vs. Forward Current



Forward Current vs. Ambient Temperature

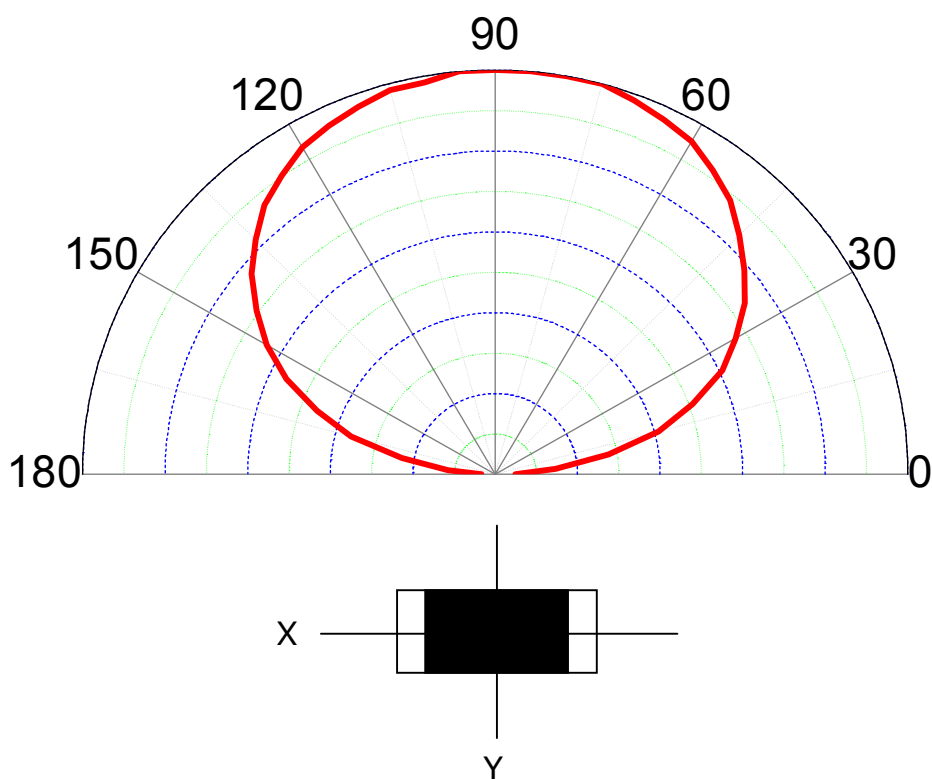


Spectrum



Radiation Diagram

$T_a = 25^\circ$



5. Reliability Test

Item	Test Conditions	Duration / Cycle	Number Of Damaged
Operating at Room temperature	20mA, @25℃	500 hrs	0/22
Operating at High temperature	20mA, @85℃	500 hrs	0/22
Operating at High temperature / High humidity	20mA, @60℃,90%	500 hrs	0/22
Thermal shock test	-40~85℃ Shift (2hr/cycle)	100 cycle	0/22
Thermal resistance Test	85℃, 85% 24hrs → Reflow 3 times (Max 260℃ 10sec) → Thermal shock 30 cycle	1 time	0/22

MSL : 2a (30℃, 60% : 4 weeks)

*Criterion

	OK
I _v	> Initial value * 0.5
V _F	Initial value ± 0.1V

6. Rank

 $I_F = 20\text{mA}$

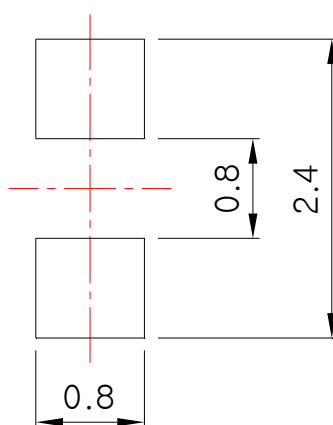
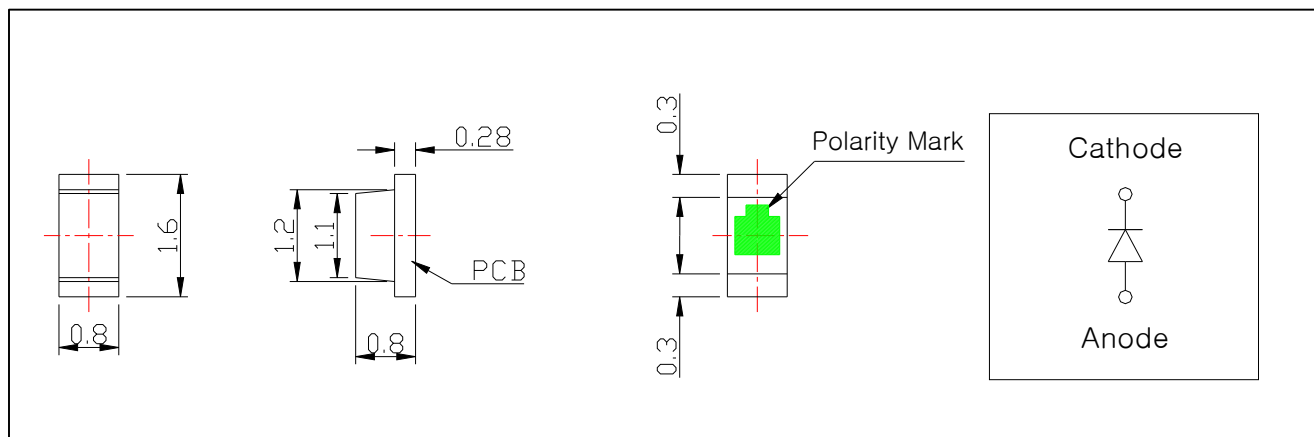
BIN	V_F [V]	W_D [nm]	I_V [mcd]
AAA	1.9~2.1 (A)	568.0~568.5 (A)	30~36 (A)
ABA	1.9~2.1 (A)	568.5~569.0 (B)	30~36 (A)
ACA	1.9~2.1 (A)	569.0~569.5 (C)	30~36 (A)
ADA	1.9~2.1 (A)	569.5~570.0 (D)	30~36 (A)
AEA	1.9~2.1 (A)	570.0~570.5 (E)	30~36 (A)
AFA	1.9~2.1 (A)	570.5~571.0 (F)	30~36 (A)
AGA	1.9~2.1 (A)	571.0~571.5 (G)	30~36 (A)
AHA	1.9~2.1 (A)	571.5~572.0 (H)	30~36 (A)
AIA	1.9~2.1 (A)	572.0~574.0 (I)	30~36 (A)
AJA	1.9~2.1 (A)	574.0~576.0 (J)	30~36 (A)
AAB	1.9~2.1 (A)	568.0~568.5 (A)	36~43 (B)
ABB	1.9~2.1 (A)	568.5~569.0 (B)	36~43 (B)
ACB	1.9~2.1 (A)	569.0~569.5 (C)	36~43 (B)
ADB	1.9~2.1 (A)	569.5~570.0 (D)	36~43 (B)
AEB	1.9~2.1 (A)	570.0~570.5 (E)	36~43 (B)
AFB	1.9~2.1 (A)	570.5~571.0 (F)	36~43 (B)
AGB	1.9~2.1 (A)	571.0~571.5 (G)	36~43 (B)
AHB	1.9~2.1 (A)	571.5~572.0 (H)	36~43 (B)
AIB	1.9~2.1 (A)	572.0~574.0 (I)	36~43 (B)
AJB	1.9~2.1 (A)	574.0~576.0 (J)	36~43 (B)
AAC	1.9~2.1 (A)	568.0~568.5 (A)	43~53 (C)
ABC	1.9~2.1 (A)	568.5~569.0 (B)	43~53 (C)
ACC	1.9~2.1 (A)	569.0~569.5 (C)	43~53 (C)
ADC	1.9~2.1 (A)	569.5~570.0 (D)	43~53 (C)
AEC	1.9~2.1 (A)	570.0~570.5 (E)	43~53 (C)
AFC	1.9~2.1 (A)	570.5~571.0 (F)	43~53 (C)
AGC	1.9~2.1 (A)	571.0~571.5 (G)	43~53 (C)
AHC	1.9~2.1 (A)	571.5~572.0 (H)	43~53 (C)
AIC	1.9~2.1 (A)	572.0~574.0 (I)	43~53 (C)
AJC	1.9~2.1 (A)	574.0~576.0 (J)	43~53 (C)

$I_F = 20\text{mA}$

BIN	V_F [V]	W_D [nm]	I_V [mcd]
BAA	2.1~2.3 (B)	568.0~568.5 (A)	30~36 (A)
BBA	2.1~2.3 (B)	568.5~569.0 (B)	30~36 (A)
BCA	2.1~2.3 (B)	569.0~569.5 (C)	30~36 (A)
BDA	2.1~2.3 (B)	569.5~570.0 (D)	30~36 (A)
BEA	2.1~2.3 (B)	570.0~570.5 (E)	30~36 (A)
BFA	2.1~2.3 (B)	570.5~571.0 (F)	30~36 (A)
BGA	2.1~2.3 (B)	571.0~571.5 (G)	30~36 (A)
BHA	2.1~2.3 (B)	571.5~572.0 (H)	30~36 (A)
BIA	2.1~2.3 (B)	572.0~574.0 (I)	30~36 (A)
BJA	2.1~2.3 (B)	574.0~576.0 (J)	30~36 (A)
BAB	2.1~2.3 (B)	568.0~568.5 (A)	36~43 (B)
BBB	2.1~2.3 (B)	568.5~569.0 (B)	36~43 (B)
BCB	2.1~2.3 (B)	569.0~569.5 (C)	36~43 (B)
BDB	2.1~2.3 (B)	569.5~570.0 (D)	36~43 (B)
BEB	2.1~2.3 (B)	570.0~570.5 (E)	36~43 (B)
BFB	2.1~2.3 (B)	570.5~571.0 (F)	36~43 (B)
BGB	2.1~2.3 (B)	571.0~571.5 (G)	36~43 (B)
BHB	2.1~2.3 (B)	571.5~572.0 (H)	36~43 (B)
BIB	2.1~2.3 (B)	572.0~574.0 (I)	36~43 (B)
BJB	2.1~2.3 (B)	574.0~576.0 (J)	36~43 (B)
BAC	2.1~2.3 (B)	568.0~568.5 (A)	43~53 (C)
BBC	2.1~2.3 (B)	568.5~569.0 (B)	43~53 (C)
BCC	2.1~2.3 (B)	569.0~569.5 (C)	43~53 (C)
BDC	2.1~2.3 (B)	569.5~570.0 (D)	43~53 (C)
BEC	2.1~2.3 (B)	570.0~570.5 (E)	43~53 (C)
BFC	2.1~2.3 (B)	570.5~571.0 (F)	43~53 (C)
BGC	2.1~2.3 (B)	571.0~571.5 (G)	43~53 (C)
BHC	2.1~2.3 (B)	571.5~572.0 (H)	43~53 (C)
BIC	2.1~2.3 (B)	572.0~574.0 (I)	43~53 (C)
BJC	2.1~2.3 (B)	574.0~576.0 (J)	43~53 (C)

7. Outline Dimension

Tolerance ± 0.1 , Unit : mm



[Recommended Solder Pattern]

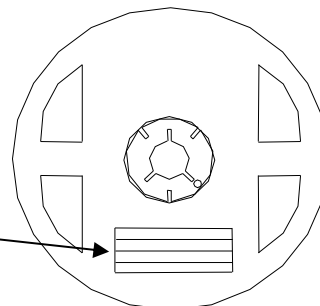
8. Material

Item	Substrate	chip	wire	Encapsulate	Electrode
Material	BT-Resin PCB	AlInGaP	Gold	Epoxy	Au Plated

10. Packing

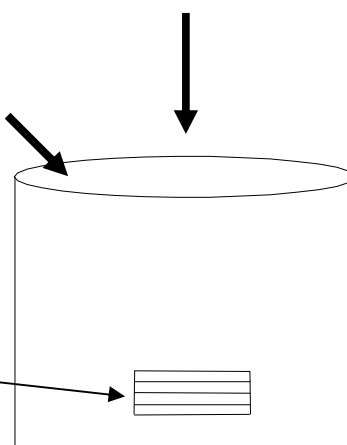
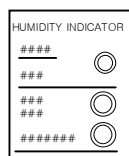
Reel

RANK: **XXX**
 QUANTITY : XXXX
 LOT NUMBER : XXXXXXXXXXXX
 PART NUMBER : **XXXXXX**
 SEOUL SEMICONDUCTOR CO., LTD.



Aluminum Vinyl Bag

RANK: **XXX**
 QUANTITY : XXXX
 LOT NUMBER : XXXXXXXXXXXX
 PART NUMBER : **XXXXXX**
 SEOUL SEMICONDUCTOR CO., LTD.



Outer Box Structure

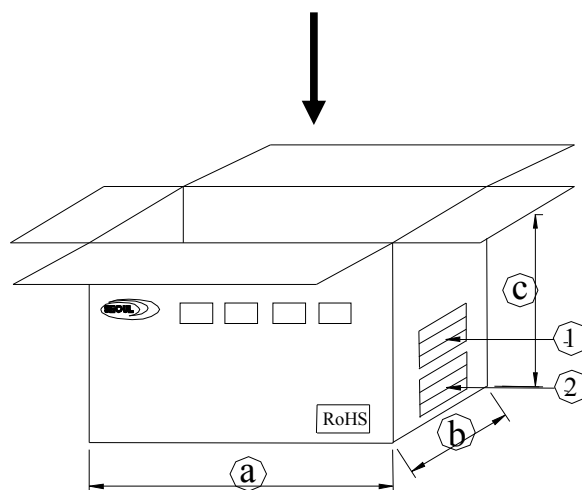
① SIDE

RANK:
 QUANTITY : XXXX
 LOT NUMBER : XXXXXXXXXXXX
 PART NUMBER : **XXXXXX**
 SEOUL SEMICONDUCTOR CO., LTD.

② SIDE

LOT NUMBER	Rank	QTY

SEOUL SEMICONDUCTOR CO., LTD.



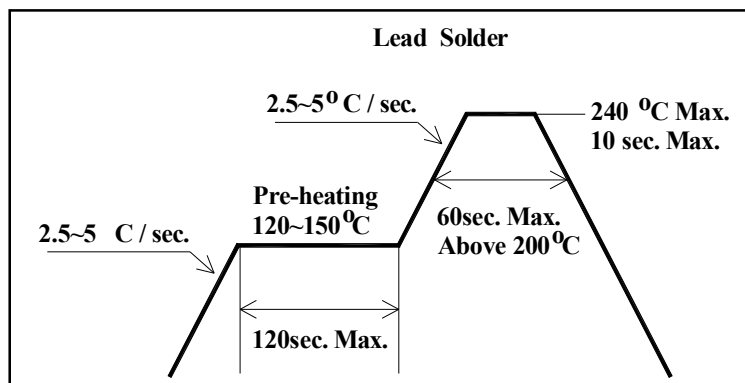
Material : Paper(SW3B(B))

TYPE	SIZE (mm)		
	a	b	c
7inch	245	220	142

11. Soldering profile

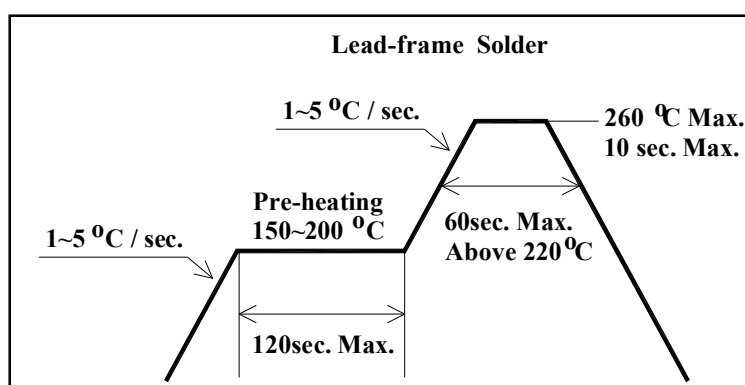
(1) Lead Solder

Lead Solder	
Pre-heat	120~150℃
Pre-heat time	120 sec. Max.
Peak-Temperature	240℃ Max.
Soldering time Condition	10 sec. Max.



(2) Lead-Free Solder

Lead Free Solder	
Pre-heat	150~200℃
Pre-heat time	120 sec. Max.
Peak-Temperature	260℃ Max.
Soldering time Condition	10 sec. Max.



(3) Hand Soldering conditions

Do not exceed 3 seconds at maximum 280℃ under soldering iron.

Note : In case that the soldered products are reused in soldering process, we don't guarantee the products.

12. Precaution for Use

(1) Storage

LEDs must be stored at clean atmosphere. If the LEDs are stored for 3 months or more after shipment from SSC, storage in a sealed container with a nitrogen atmosphere is recommended. To avoid absorption of moisture, it is recommended to store in a dry box (or a desiccator) with a desiccant.

* Shelf Life : 12 months at < 40°C and 90%RH

(2) Attention after open.

LED is correspond to SMD, when LED be soldered dip, interfacial separation may affect the light transmission efficiency, causing the light intensity to drop. After opened and mounted the soldering shall be quickly.

* Within 672 hours at factory conditions of equal to or less than 30°C/60%RH, or
Stored at < 10% RH

(3) Repack unused products with anti-moisture packing, fold to close any opening and then store in a dry place.

(4) In the case of change color of indicator on desiccant, components shall be dried 10-12hr at 60±5°C.

(5) When the LED is operating, the driving current should be determined after considering the maximum ambient temperature requirements.

(6) When using multiple LEDs, It is recommended to connect a resistor on each LED. Otherwise, LEDs may vary due to variation in forward voltage of the LEDs.

(7) The driving circuit must be designed to allow forward voltage only when it is ON or OFF. If the reverse voltage is applied to LED, migration can be generated resulting in LED damage

(8) Any mechanical force or excessive vibration should be avoided during temperature cooling process to normal temperature after reflow.

(9) Rapid cooling shall be avoided.

(10) LED should not be placed on a flexible area on the PCB.

(11) This device should not be used in any type of fluid such as water, oil, organic solvent etc. When washing is required, IPA should be used.

(12) Anti radioactive ray design is not considered for the products.

(13) Damage prevention from ESD or Surge.

It is highly recommended to use the wrist-band or anti electrostatic gloves when handling the LED's All devices, equipments and machines must be properly grounded

(14) The appearance and specifications of the product may be modified for improvement without notice.